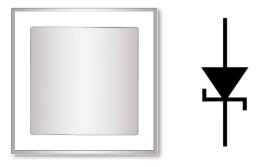


Gen 2 Silicon Carbide Schottky Diode

Description

This is the 2nd generation of high voltage, high performance Z-Rec® silicon carbide Schottky diode in a packageless bare die format to be implemented into any custom module design. The lower forward voltage, smaller reverse leakage current, zero reverse recovery, and high thermal conductivity make this Schottky diode ideal for high frequency switching applications including solar inverters. This Schottky diode can be used in conjunction with either IGBT or MOSFET as an anti-parallel diode, or as a rectifier.



Package Type: Bare Die PN's: CPW2-0600-S010B

Features

- 600V Schottky Rectifier
- Zero Reverse Recovery
- Zero Forward Recovery
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Applications

- Power factor correction
- Solar inverter
- UPS
- SMPS

Absolute Maximum Ratings

Stress beyond those listed under absolute maximum ratings may damage the device.

Parameter	Symbol		Rating	Unit
Repetitive Peak Reverse Voltage	V _{RRM}		600	V
Continuous Forward Current	I _F	$T_c = 25^{\circ}C$	30	A
		T _c = 135°C	14.5	
		T _c = 153°C	10	
Repetitive Peak Forward Surge Current, assumes t _p = 10ms,	I _{FRM}	$T_c = 25^{\circ}C$	46	A
Half Sine Wave Pulse		T _c = 110°C	31	
Non-Repetitive Forward Surge Current, assumes t _p = 10ms,		$T_c = 25^{\circ}C$	90	_
Half Sine Wave Pulse	I _{FSM}	T _c = 110°C	71	A
Virtual Junction and Storage Temperature	T _{VJ} , T _{stg}		-55 to +175	°C
Maximum Processing Temperature, in non-reactive ambient	T_{proc}		325	°C

Note: All above notation to T_c specifies case temperature from die packaged in TO-247, with $Rth(j-c) < 1.1^{\circ}C/W$

Electrical Characteristics (T_{VJ} = 25°C)

Parameter	Symbol	Тур.	Max.	Unit	Test Conditions
Forward Voltage	V	1.5	1.8		I _F = 8 A
	V _f	2	2.4	- V	I _F = 8 A, T _{VJ} = 175°C
David Company	10 50		V _R = 600 V		
Reverse Current	IR	20	200	μΑ	V _R = 600 V, T _{VJ} = 175°C
Total Capacitive Charge	Qc	24		nC	V _R = 400 V
Total Capacitance		460.5			V _R = 0 V, f = 1Mhz
	С	44		pF	V _R = 200 V, f = 1Mhz
		40			V _R = 400 V, f = 1Mhz
Capacitance Stored Energy	Ec	3.6		μJ	V _R = 400 V

Thermal Characteristics

Parameter	Symbol	Typical	Unit
Thermal Resistance from Junction to Case ¹	R _{th(j-c)}	1.1	°C/W

Note:

¹Tested in TO-247 Package

Typical Performance

All the graphs are based on a die placed in a TO-247 package.

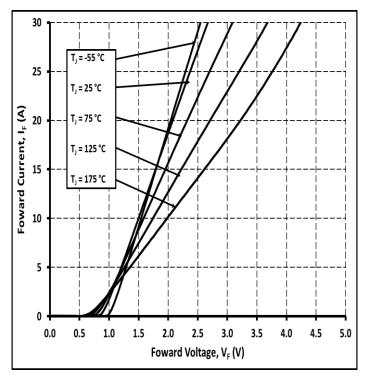


Figure 1.

Typical Forward Characteristics

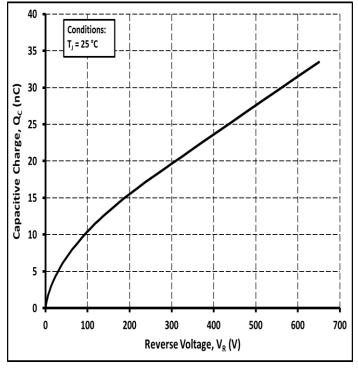


Figure 3.

Typical Capacitance vs Reverse Voltage

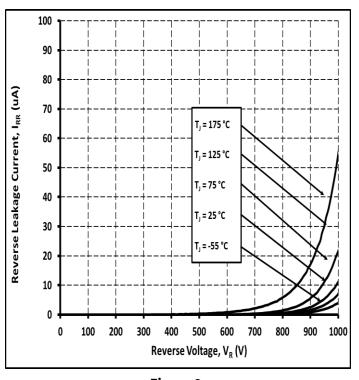


Figure 2.

Typical Reverse Characteristics

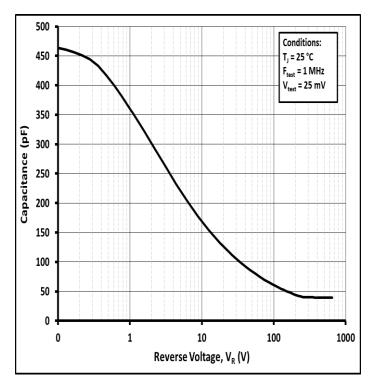
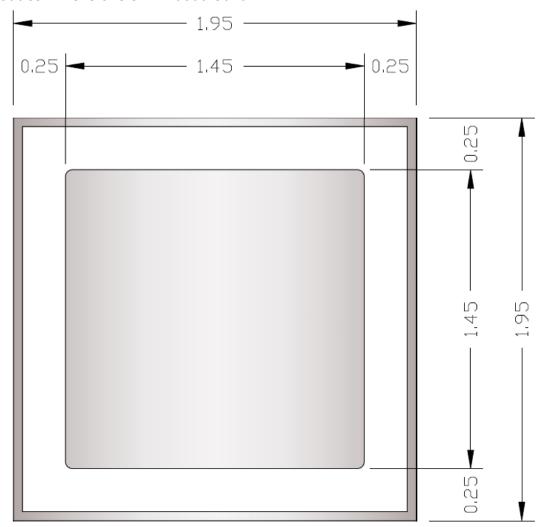


Figure 4.

Typical Recovery Charge vs Reverse Voltage

Product Dimensions CPW2-0600-S010B



Product Dimensions CPW2-0600-S010B

Parameter	Typical	Units
Die Size (L x W)	1.95 x 1.95	mm
Anode Pad Opening	1.45 x 1.45	mm
Die Thickness ¹	377 ± 10%	μm
Topside Anode Metalization (Al)	4	μm
Backside Cathode Metalization (Au)	1.8	μm
Frontside Passivation (polymide)	Polyimide	

¹SiC Thickness

Product Ordering Information

Order Number	Description	Package
CPW2-0600-S010B-FU6	SiC Diode G2 IND 600V/10A FULL MLT	Bare Die Product

Revision History

Revision History	Date of Change	Brief Summary
6	9/1/2023	Template updated

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Contact info:

4600 Silicon Drive Durham, NC 27703 USA Tel: +1.919.313.5300 www.wolfspeed.com/power

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